Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
60V	3.7mΩ@10V	110A

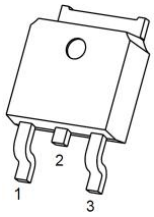
Feature

- Fast Switching
- Low Gate Charge and Rdson
- Advanced Split Gate Trench Technology
- 100% Single Pulse avalanche energy Test

Applications

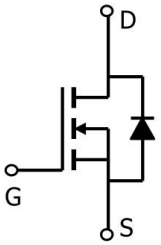
- DC-DC Converters
- Power Management

Package

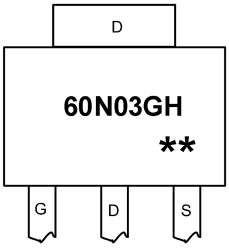


TO-252-2L(G:1 D:2 S:3)

Circuit diagram



Marking



60N03GH =Device Code
**** =Week Code**

Absolute maximum ratings (Ta=25℃ unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current1 (Tc=25℃)	I_D	110	A
Pulsed Drain Current[2]	I_{DM}	440	A
Single Pulse Avalanche Energy[3]	E_{AS}	756	mJ
Total Power Dissipation[4] (Tc=25℃)	P_D	110	W
Thermal Resistance Junction-Case[1]	$R_{\theta JC}$	1.13	℃/W
Storage Temperature Range	T_{STG}	-55 to 150	℃
Operating Junction Temperature Range	T_J	-55 to 150	℃

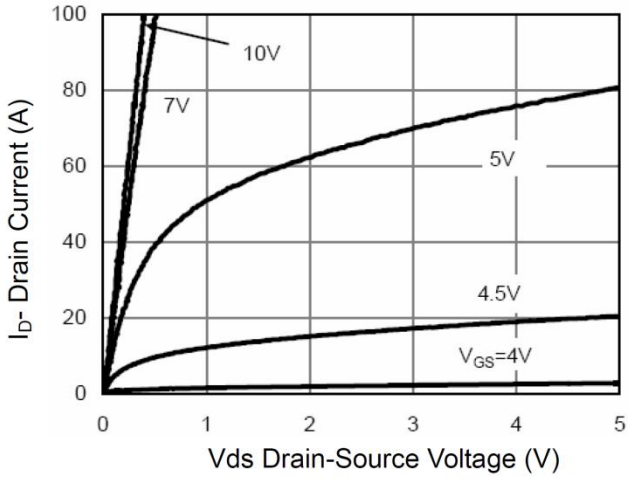
Electrical characteristics (Ta=25℃, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	VGS=0V , ID=250uA	60	---	---	V
Drain-Source Leakage Current	I_{DSS}	VDS=48V , VGS=0V	---	---	1	uA
Gate-Source Leakage Current	I_{GSS}	VGS=±20V , VDS=0V	---	---	±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	VGS=VDS , ID =250uA	2.0	2.5	4.0	V
Static Drain-Source On-Resistance[2]	$R_{DS(ON)}$	VGS=10V , ID=20A	---	3.7	4.7	mΩ
Dynamic characteristics						
Input Capacitance	C_{iss}	VDS=30V , VGS=0V , f=1MHz	---	4250	---	pF
Output Capacitance	C_{oss}		---	975	---	
Reverse Transfer Capacitance	C_{rss}		---	41	---	
Switching Characteristics						
Total Gate Charge	Q_g	VDS=30V , VGS=10V , ID=20A	---	68	---	nC
Gate-Source Charge	Q_{gs}		---	19	---	
Gate-Drain Charge	Q_{gd}		---	14	---	
Turn-On Delay Time	$T_{d(on)}$	VDD=30V , VGS=10V , RG=4.7Ω, ID=20A	---	6	---	ns
Rise Time	T_r		---	12	---	
Turn-Off Delay Time	$T_{d(off)}$		---	24	---	
Fall Time	T_f		---	5	---	
Diode Characteristics						
Diode Forward Voltage2	V_{SD}	VGS=0V , IS=1A , TJ=25℃	---	---	1.2	V

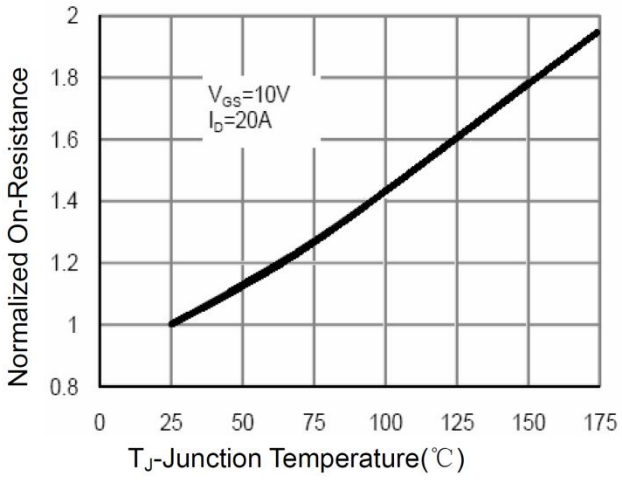
Note :

1. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper.
2. The data tested by pulsed , pulse width ≦ 300us , duty cycle ≦ 2%
3. The EAS data shows Max. rating . The test condition is VDD=30V,VGS=10V,L=0.5mH,RG=25Ω
4. The power dissipation is limited by 150℃ junction temperature
5. The data is theoretically the same as ID and IDM , in real applications , should be limited by total power dissipation.

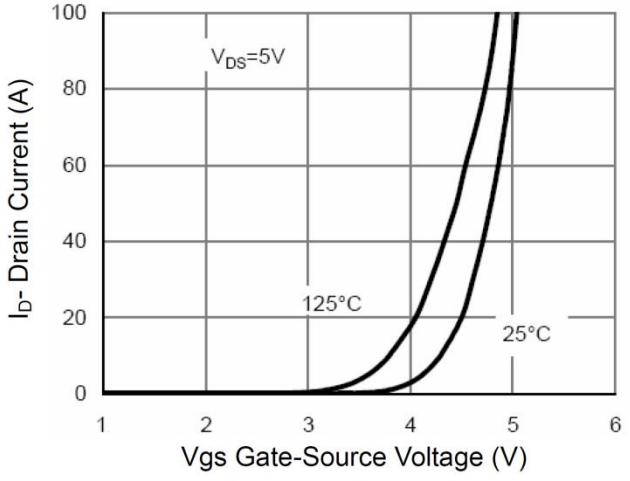
Typical Characteristics



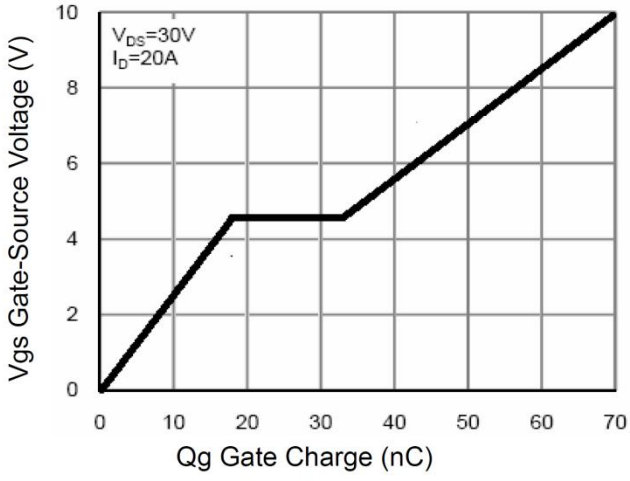
Output Characteristics



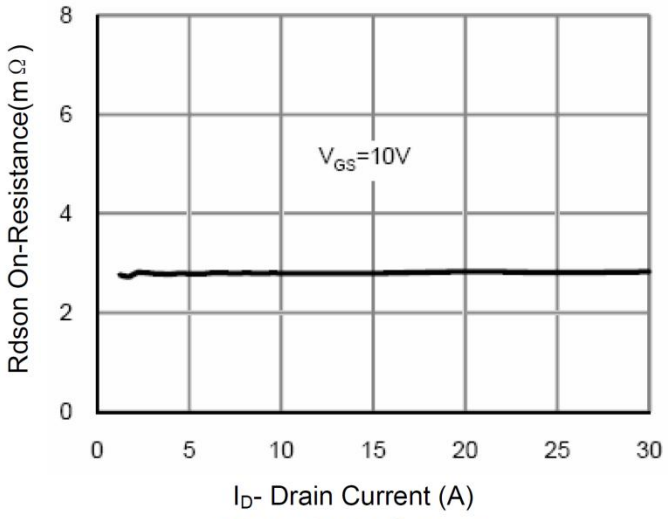
Rdson-Junction Temperature



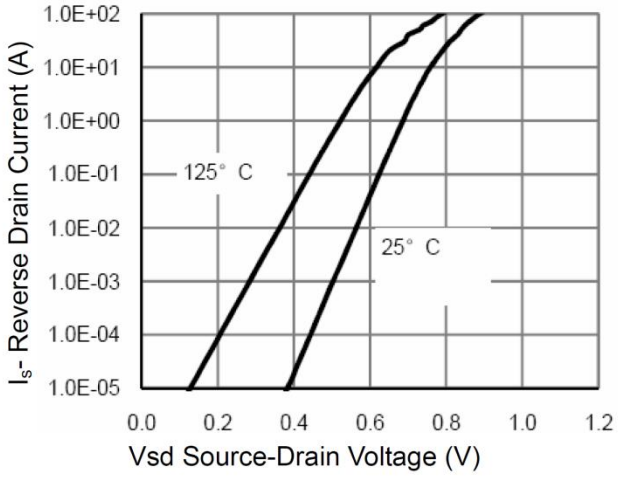
Transfer Characteristics



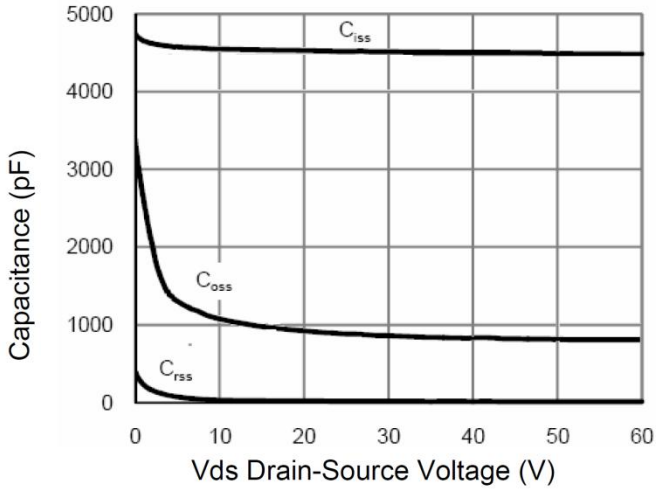
Gate Charge



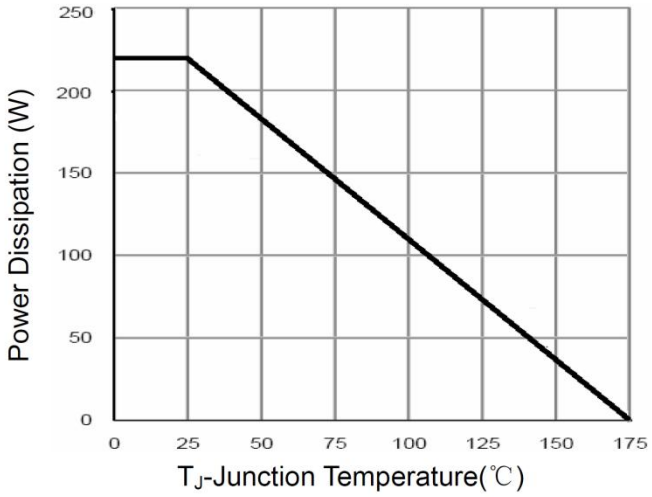
Rdson- Drain Current



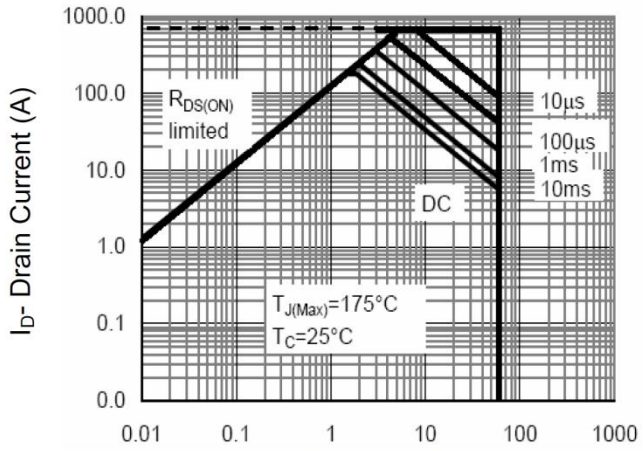
Source- Drain Diode Forward



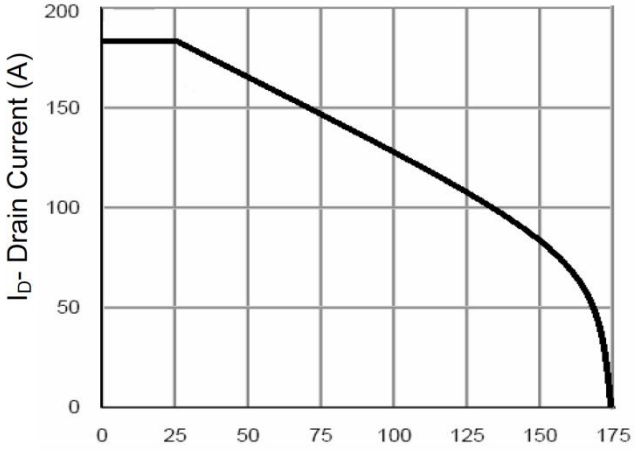
Capacitance vs Vds



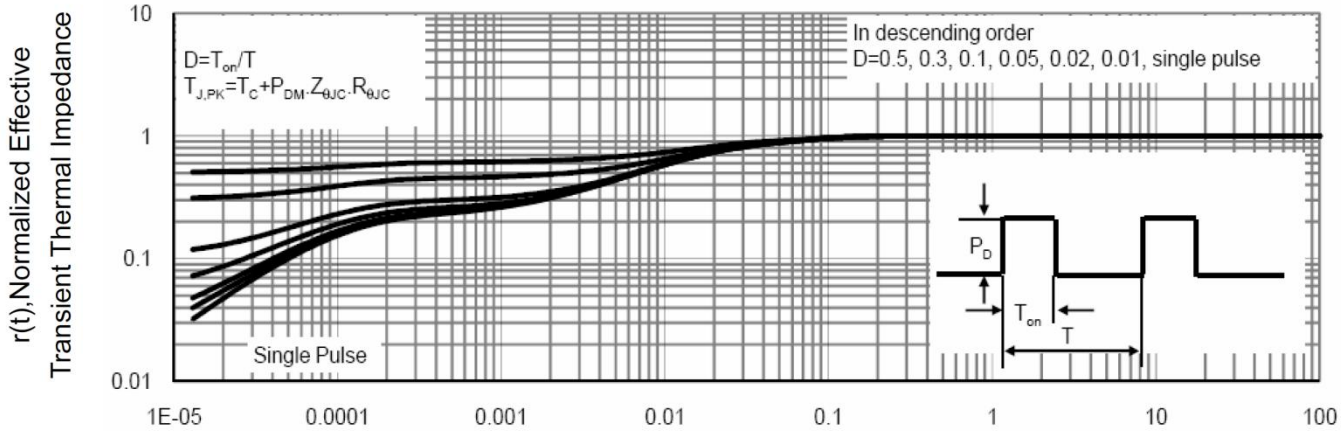
Power De-rating



Safe Operation Area

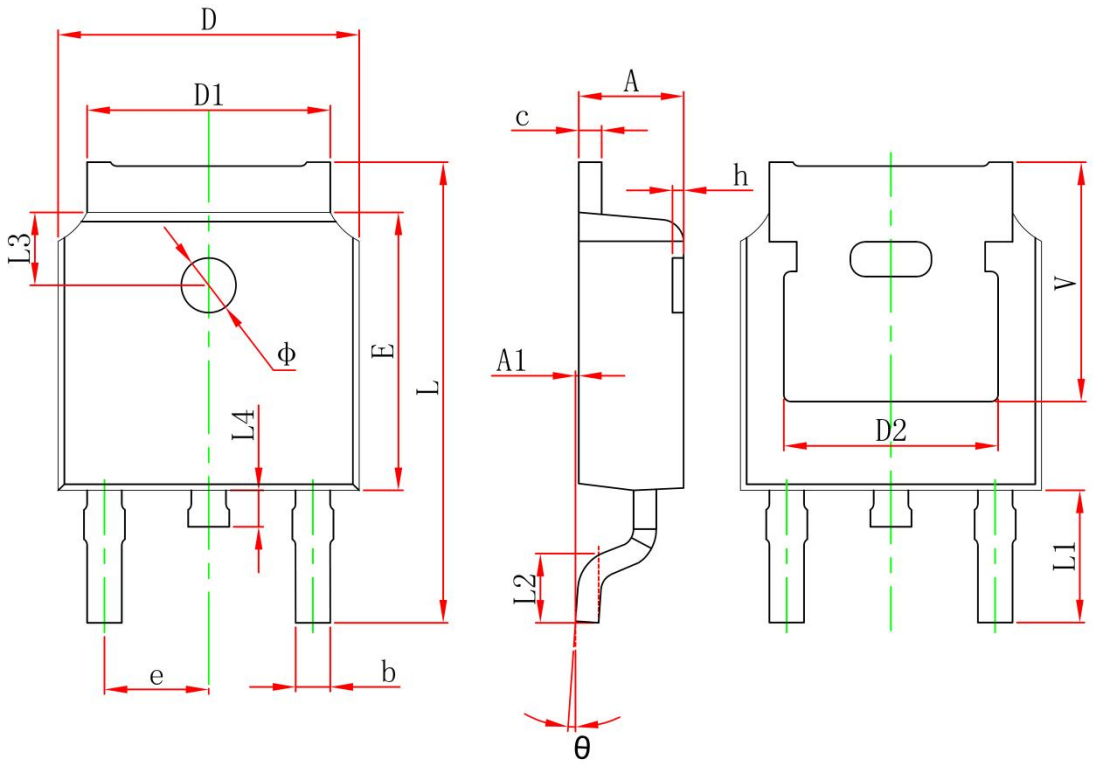


Current De-rating



Normalized Maximum Transient Thermal Impedance

TO-252 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.660	0.860	0.026	0.034
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.350 REF.		0.211 REF.	

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